

## Solid State Broadband High Power Amplifier

**1184 - BBM3O6QCK**
**700 – 3800 MHz / 15 Watts**

The BBM3O6QCK (SKU 1184) is suitable for broadband mobile Jamming and band specific high power linear applications in the P/L/S frequency bands. This compact module utilizes high power advanced GaN devices that provide excellent power density, high efficiency, wide dynamic range and low distortions. Exceptional performance, long term reliability and high efficiency are achieved by employing advanced broadband RF matching networks and combining techniques, EMI/RFI filters, machined housings and qualified components. Empower RF's ISO9001 Quality Assurance Program assures consistent performance and the highest reliability.



- Solid-state class AB design
- Instantaneous ultra broadband
- Small and lightweight
- Suitable for CW, AM, and FM (Consult factory for other modulation types)
- 50 ohm input/output impedance
- High reliability and ruggedness
- Built-in control, monitoring and protection circuits

### ELECTRICAL SPECIFICATIONS @ +28V<sub>DC</sub>, 25°C, 50Ω System

Parameter	Symbol	Min	Typ	Max	Unit
Operating Frequency	BW	700		3800	MHz
Power Output CW	P <sub>SAT</sub>	15			Watt
Output Power @ 1dB Gain Compression	P <sub>1dB</sub>		6		Watt
Small Signal Gain	G <sub>SS</sub>	42		48	dB
Input Power for Rated P <sub>SAT</sub>	P <sub>IN</sub>		0	3	dBm
Gain Flatness @ Rated P <sub>SAT</sub>	ΔG <sub>P</sub>		±1.0	±1.5	dB
Input Return Loss	S <sub>11</sub>			-10	dB
Noise Figure	NF			10	dB
Third Order Intercept Point 2-Tone @ 30dBm/Tone, 100kHz Spacing	IP3		+40		dBm
Harmonics @ P <sub>OUT</sub> = 6W	H		-25	-15	dBc
Spurious Signals	Spur		-70	-60	dBc
Operating Voltage	V <sub>DC</sub>	26	28	30	Volt
Current Consumption @ P <sub>OUT</sub> = 15W	I <sub>DD</sub>			3.0	Amp
Current Consumption @ Shutdown	I <sub>DQ</sub>		100		mA
Switching Time, 1kHz TTL, P <sub>IN</sub> = 0dBm	T <sub>ON</sub> /T <sub>OFF</sub>		2.0	5.0	uSec

### MECHANICAL SPECIFICATIONS

Parameter	Value	Unit
Dimensions	6.0 x 3.0 x 1.0	Inch
Weight	1.0	Pound
RF Connectors Input/Output	Type-SMA, Female	
DC Interface Connector	D-Sub 9-Pin, Male	
Cooling	External Heatsink (Not Supplied)	

### ENVIRONMENTAL CHARACTERISTICS (Design to Meet)

Parameter	Symbol	Min	Typ	Max	Unit
Operating Case Temperature	T <sub>C</sub>	-20		+75	°C
Non-operating Temperature	T <sub>STG</sub>	-40		+85	°C
Relative Humidity (non-condensing)	RH			95	%
Altitude (MIL-STD-810F Method 500.4)	ALT			30,000	Feet
Vibration/Shock MIL-STD-810F - Method 51405/516.5 – Proc I	VI/SH		Airborne		

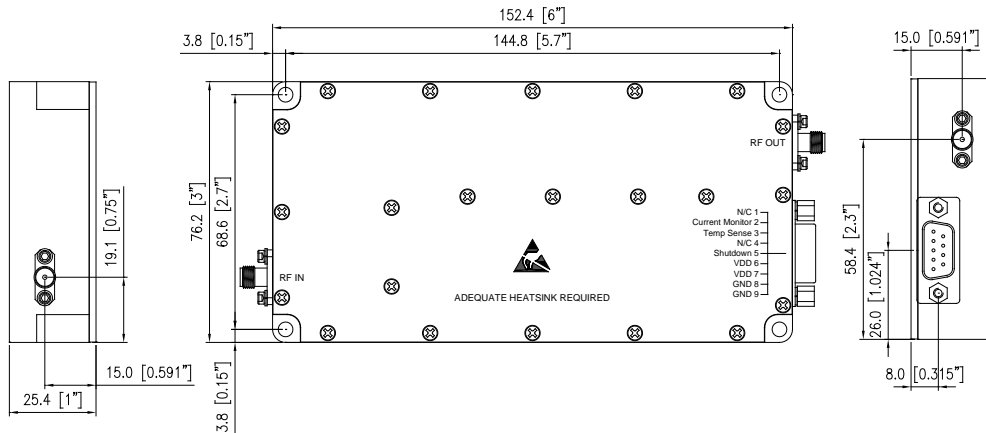
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**LIMITS**

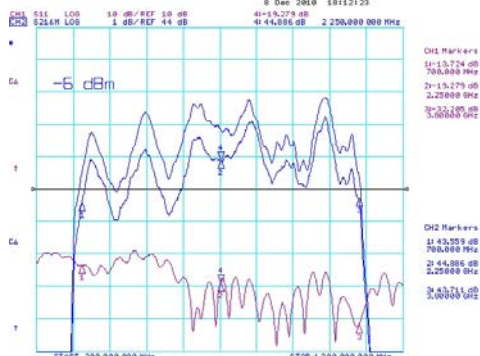
Input RF drive level without damage	+10 dBm	Max
Load VSWR @ P <sub>OUT</sub> = 15W	∞ @ all load phase & amplitude for duration of 1 minute 3:1 @ all load phase & amplitude continuous	-
Thermal Overload	85°C	Typ

**DC INTERFACE CONNECTOR – D-Sub 9-Pin, Male**

Pin #	Description	Specification
1	N/C	No Connection
2	Current Monitor	Analog voltage relative to I <sub>DD</sub> @ 100mV/100mA
3	Temperature Sense	Analog voltage relative to Module's Temperature @ 10mV/°C (e.g. 0.25V <sub>DC</sub> = 25°C)
4	N/C	No Connection
5	Shutdown	Amplifier Disable: TTL Logic High (5V) (Internally Pulled-Low)
6&7	VDD	+26.0-30.0V <sub>DC</sub>
8&9	GND	Ground

**OUTLINE DRAWING**

**PERFORMANCE PLOTS**
**Plot 1 – Small Signal Gain and P<sub>1dB</sub>**

Top Curve: Small Signal Gain @ P<sub>IN</sub> = -20dBm  
 Middle Curve: Power Gain @ P<sub>1dB</sub>, P<sub>IN</sub> = -6dBm  
 Reference: 44dB, 1dB/div.  
 Bottom Curve: Input Return Loss  
 Reference: 10dB, 10dB/div.


**Plot 2 – Small Signal Gain and P<sub>SAT</sub>**

Top Curve: Small Signal Gain @ P<sub>IN</sub> = -20dBm  
 Middle Curve: Power Gain @ P<sub>SAT</sub>, P<sub>IN</sub> = +1dBm  
 Reference: 43dB, 1dB/div.  
 Bottom Curve: Input Return Loss  
 Reference: 10dB, 10dB/div.

